

## **NCE N-Channel Super Trench Power MOSFET**

#### **Description**

The NCEP0112AS uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS}(\text{ON})}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **General Features**

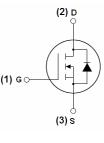
•  $V_{DS}$  =100V, $I_D$  =12A  $R_{DS(ON)}$ =9.9m $\Omega$  (typical) @  $V_{GS}$ =10V  $R_{DS(ON)}$ =11.5m $\Omega$  (typical) @  $V_{GS}$ =4.5V

- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

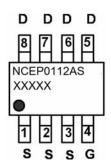
#### **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

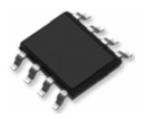
100% UIS TESTED!



#### Schematic diagram



Marking and pin assignment



SOP-8 top view

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP0112AS	NCEP0112AS	SOP-8	Ø330mm	12mm	4000 units

### Absolute Maximum Ratings (T<sub>A</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	100	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	12	А
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	8	Α
Pulsed Drain Current	I <sub>DM</sub>	48	Α
Maximum Power Dissipation	P <sub>D</sub>	3.5	W
Derating factor		0.028	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	152	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$



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# NCEP0112AS

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	36	°C/W	1
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Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Symbol Condition		Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	100	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =100V,V <sub>GS</sub> =0V	-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±100	nA
On Characteristics (Note 3)	<u> </u>		•			
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.0	1.7	2.2	V
Drain-Source On-State Resistance		V <sub>GS</sub> =10V, I <sub>D</sub> =12A	-	9.9	13	mΩ
	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =12A	-	11.5	15	mΩ
Gate resistance	R <sub>G</sub>		-	7.0	-	Ω
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =12A	-	30	-	S
Dynamic Characteristics (Note4)			1	<u>I</u>		
Input Capacitance	C <sub>lss</sub>		-	3773	-	PF
Output Capacitance	Coss	$V_{DS}$ =50V, $V_{GS}$ =0V,	-	287	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	19.7	-	PF
Switching Characteristics (Note 4)			1			
Turn-on Delay Time	t <sub>d(on)</sub>		-	11	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =50 $V$ , $I_D$ =12 $A$	-	7	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =1.6 $\Omega$	-	30	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	4	-	nS
Total Gate Charge	Qg		-	45	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =50V,I <sub>D</sub> =12A,	-	11.6	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	6	-	nC
Drain-Source Diode Characteristics			1			
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =12A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	12	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C$ , $I_F = I_S$	-	78	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	149	-	nC

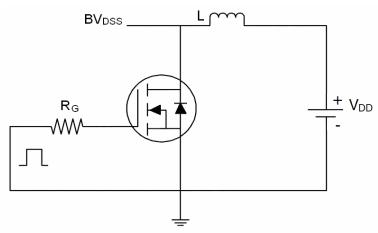
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=50V,VG=10V,L=0.5mH,Rg=25 $\Omega$

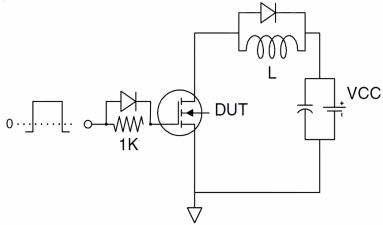


#### **Test Circuit**

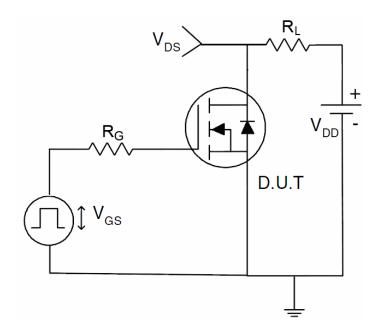
## 1) E<sub>AS</sub> test Circuit



### 2) Gate charge test Circuit

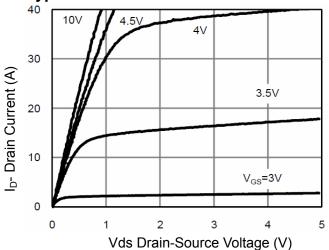


## 3) Switch Time Test Circuit

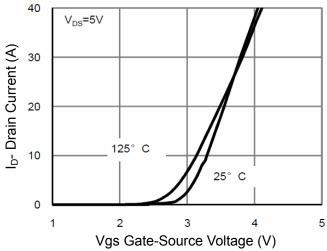








**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

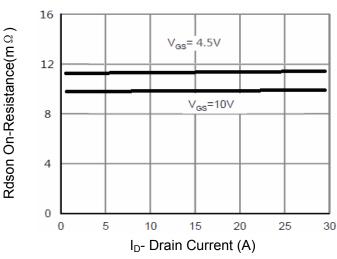
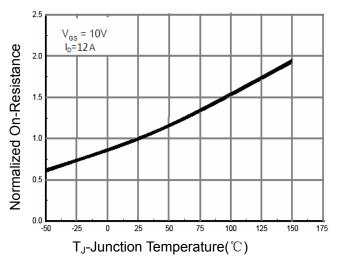


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

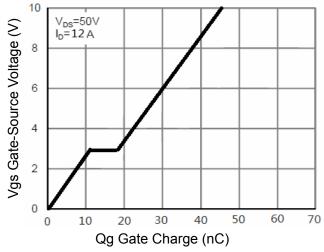


Figure 5 Gate Charge

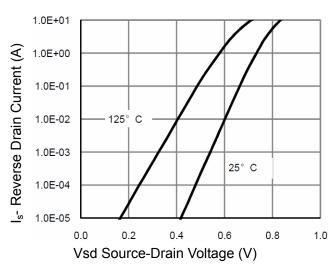


Figure 6 Source- Drain Diode Forward



Ip- Drain Current (A)

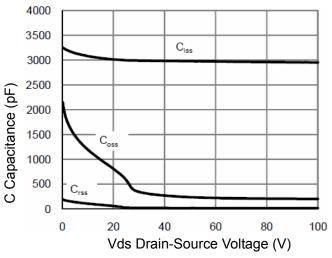


Figure 7 Capacitance vs Vds

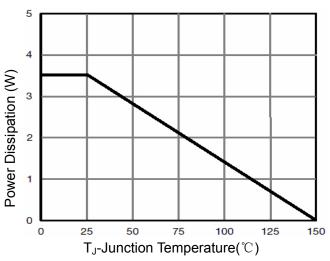


Figure 9 Power De-rating

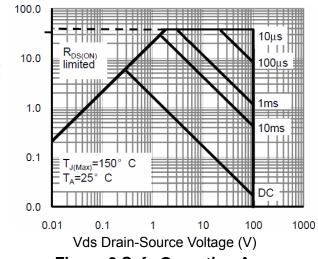


Figure 8 Safe Operation Area

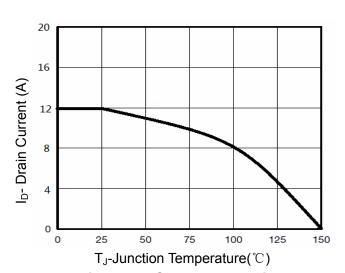
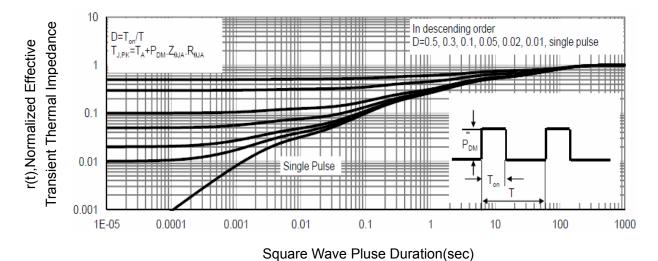


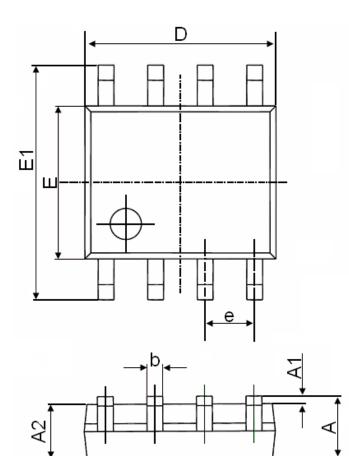
Figure 10 Current De-rating

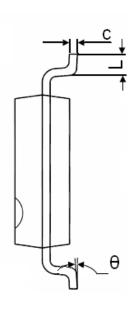


**Figure 11 Normalized Maximum Transient Thermal Impedance** 



## **SOP-8 Package Information**





Combal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
С	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
Е	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270(BSC)		0.050(E	BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	

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## NCEP0112AS

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